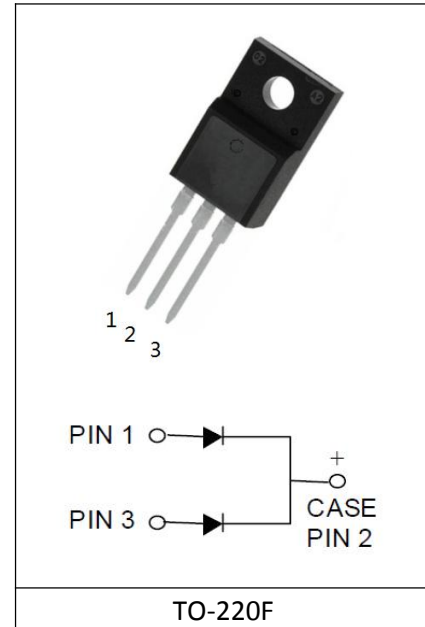


SCHOTTKY RECTIFIERS

Features:

- Low power loss,high efficiency
- High surge capacity
- For use in low voltage,high frequency inverters, free wheeling,and polarity protection applications
- Metal silicon junction,majority carrier conduction
- Guard ring for over voltage protection



Absolute Maximum Ratings(Tc=25°C):

Characteristics	Symbol	Rating	Unit
Maximum Repetitive Reverse Voltage	V_{RRM}	200	V
Average Rectified Forward Current	$I_{F(AV)}$	20	A
Non-repetitive Peak Forward Surge Current 8.3ms Single Half-Sine-Wave	I_{FSM}	135	A
Collector power dissipation	$T_a=25^{\circ}C$ P_{tot}	2.0	W
Junction temperature	T_j	175	$^{\circ}C$
Storage temperature range	T_{STG}	-55~175	$^{\circ}C$

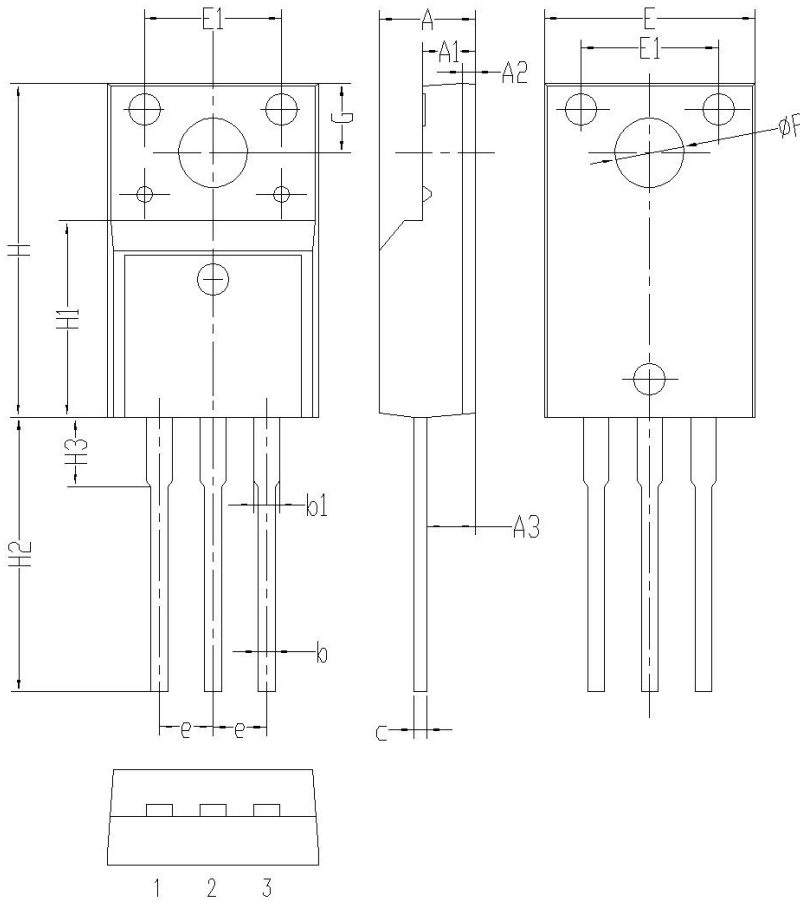
Electrical Characteristics(Tc=25°C) :

Characteristics	Symbol	Test Condition	Min	Typ	Max	Unit
Forward Voltage	V_F	$I_F=10A$; $T_C=25^{\circ}C$			0.9	V
Reverse Current	I_R	$V_R=200V$; $T_C=25^{\circ}C$ $V_R=200V$; $T_C=125^{\circ}C$			0.01 10.0	mA
Peak Repetitive Reverse Surge Current	I_{RRM}	2.0 us Pulsu Width , $f=1.0KHZ$ $T_J<175^{\circ}C$			3	A

Symbol	Paramter	Typ	Units
$R_{\theta JC}$	Junction-to-Case	1.4	$^{\circ}C/W$

Package Information

TO-220F PACKAGE



	單位: mm		
	MIN	NOM	MAX
A	4.35	4.55	4.75
A 1	2.3	2.5	2.7
A 2	0.4	0.6	0.8
A 3	2.1	2.3	2.5
b	0.6	0.8	1.0
b 1	1.0	1.2	1.4
c	0.3	0.5	0.7
e	2.3	2.5	2.7
E	9.8	10	10.2
E 1	6.3	6.5	6.7
H	15.6	15.8	16.0
H 1	8.8	9	9.2
H 2	12.9	13.2	13.5
H 3	3.1	3.3	3.5
G	3.1	3.3	3.5
ΦP	3.1	3.3	3.5